NSN 5962-01-492-5823

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
End Application:
Aircraft, starlifter c-141
Features Provided:
Ultraviolet erasable
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input
Product Name:
Microcircuit, digital memory cmos, uv erasable programming logic array
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
10.00 nanoseconds af output megawatts
Memory Device Type:
Pal
Special Features:
This is an altered item. Altered item shall be made from unprogrammed device p/n 5962-8753906lx following programming procedures
5137911-ei
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
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Demilitarization:
Yes - demil/mli
Fiig:
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